



DMN3021LFDF

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
2014	15mΩ @ V _{GS} = 10V	9.3A
30V	20mΩ @ V _{GS} = 4.5V	8.1A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

U-DFN2020-6 (Type F)

- Battery Management Application
- Power Management Functions
- DC-DC Converters

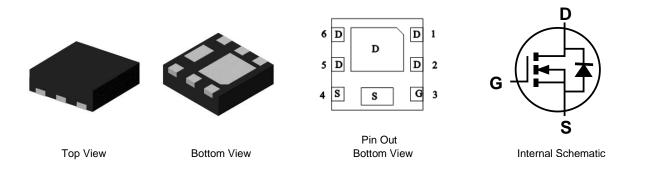
Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

30V N-CHANNEL ENHANCEMENT MODE MOSFET

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.007 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3021LFDF-7	U-DFN2020-6 (Type F)	3,000/Tape & Reel
DMN3021LFDF-13	U-DFN2020-6 (Type F)	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1



F2 = Product Type Marking Code YM = Date Code MarkingY = Year (ex: H = 2020)M = Month (ex: 9 = September)

Date Code Key

Year	2015		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	С		Н		J	К	L	М	Ν	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



F2 = Product Type Marking Code YWX = Date Code Marking

 $\begin{array}{l} Y = Y \text{ear} (\text{ex: 0} = 2020) \\ W = \text{Week} (\text{ex: a} = \text{Week 27; z Represents Week 52 and 53}) \\ X = \text{Internal Code} (\text{ex: U} = \text{Monday}) \end{array}$

Date Code Key											
Year	2015	 2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	5	 0	1	2	3	4	5	6	7	8	9

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	Х	Y	Z



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			Vgss	±20	V
	Steady State	T _A = +25°C T _A = +70°C	ID	9.3 7.5	А
Continuous Drain Current (Note 6) VGS = 10V	t<5s	T _A = +25°C T _A = +70°C	lo	11.8 9.4	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 16	%)		Ідм	50	А
Maximum Continuous Drain-Source Diode Forward	Current (Note 6))	ls	1.8	А
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	18	А		
Avalanche Energy (Note 7) L = 0.1mH			Eas	16	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Total Dower Dissinction (Note 5)	T _A = +25°C	P	0.73	14/	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.47	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Davis	174	°C/W	
Thermal Resistance, Junction to Amblent (Note 5)	t < 5s	Roja	112	C/vv	
Total Power Dissipation (Note 6)	T _A = +25°C	D -	2.03	W	
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.30	vv	
Thermal Desistance Junction to Ambient (Note 6)	Steady State	Davis	64		
Thermal Resistance, Junction to Ambient (Note 6)	t < 5s	Roja	40	°C/W	
Thermal Resistance, Junction to Case (Note 6)	Steady State	R _{ØJC}	13		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	1		1	1	r	1
Drain-Source Breakdown Voltage	BVDSS	30	_	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	_		1	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage	lgss	—		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	Vgs(th)	1.0		2.2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Proven			15	mΩ	$V_{GS} = 10V, I_D = 7A$
	R _{DS(ON)}	_		20	11112	$V_{GS} = 4.5V, I_{D} = 7A$
Diode Forward Voltage	Vsd	_	0.8	1.2	V	VGS = 0V, IS = 2.2A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	_	706	—		
Output Capacitance	Coss	—	112	—	pF	$V_{DS} = 15V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	81	—		1 = 1.000112
Gate Resistance	R _G	_	2.6	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 10V)	QG	—	14	—		
Total Gate Charge (V _{GS} = 4.5V)	QG	_	6.7	—	nC	
Gate-Source Charge	Q _{GS}	_	1.9	—	nc	VDS = 15V, ID = 5A
Gate-Drain Charge	Qgd	_	2.5	—		
Turn-On Delay Time	tD(ON)	—	5.4	—		
Turn-On Rise Time	tR	—	6.8	—	20	$V_{DS} = 15V, V_{GS} = 4.5V,$
Turn-Off Delay Time	tD(OFF)	_	9.7	—	ns	$R_g = 1.7\Omega, I_D = 5A$
Turn-Off Fall Time	tF	_	4.7	_		

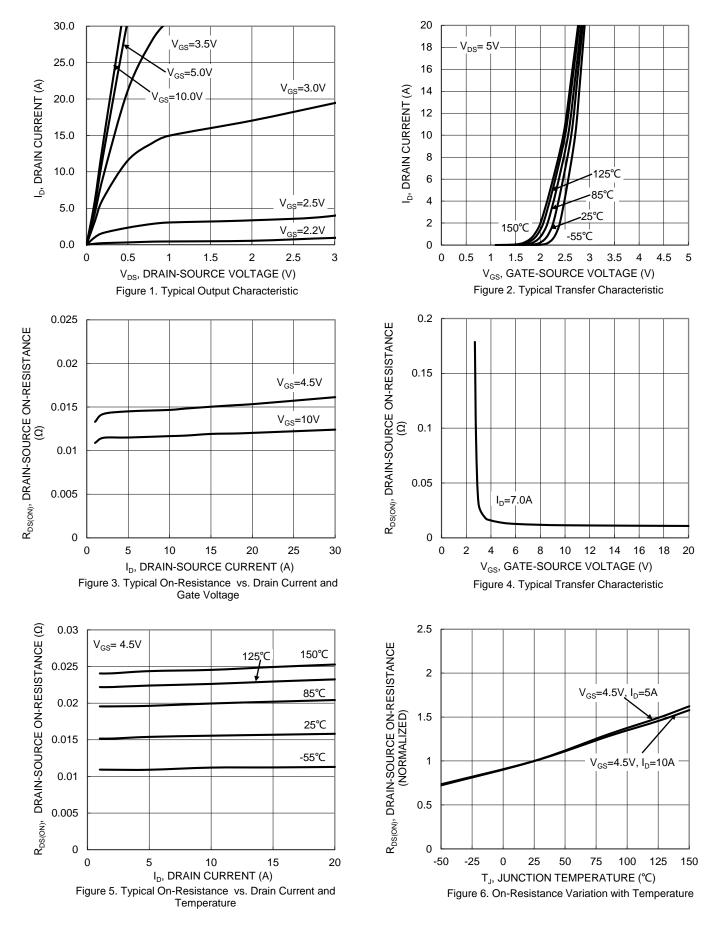
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

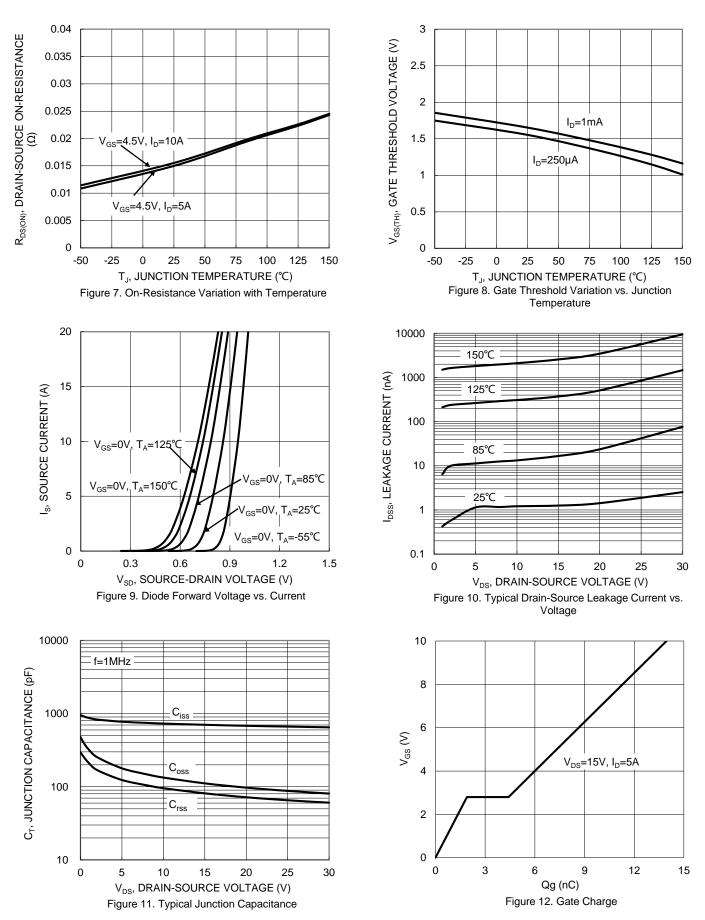


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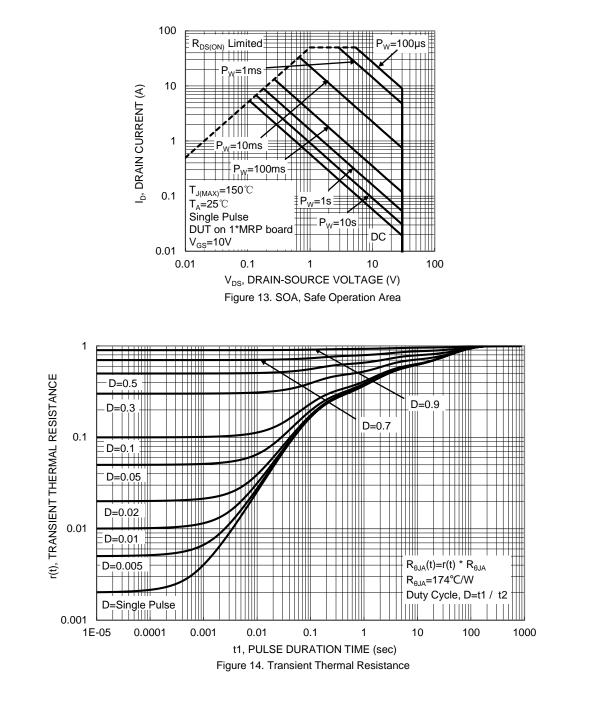
DMN3021LFDF Datasheet number: DS37731 Rev. 3 - 2







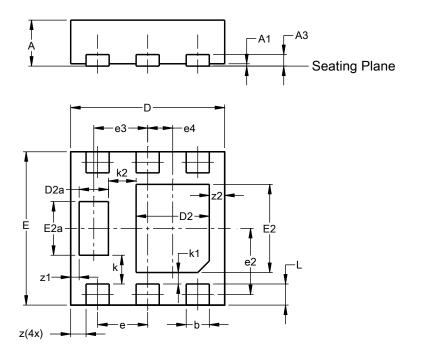






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



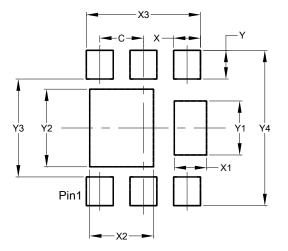
U-DFN2020-6	(Type F)
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	U-DFN	2020-6						
	(Type F)							
Dim	Min	Min Max Typ						
Α	0.57	0.63	0.60					
A1	0.00	0.05	0.03					
A3	-	-	0.15					
b	0.25	0.35	0.30					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
D2a	0.33	0.43	0.38					
E	1.95	2.05	2.00					
E2	1.05	1.25	1.15					
E2a	0.65	0.75	0.70					
е		0.65 BS	С					
e2	0).863 BS	SC					
e3		0.70 BS	С					
e4	0).325 BS	SC					
k		0.37 BS	С					
k1		0.15 BS	С					
k2		0.36 BS						
L	0.225	0.325	0.275					
z		0.20 BS	С					
z1	0).110 BS	SC					
z2		0.20 BS	С					
All C	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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